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Please find below a communication from the EXAMINER in charge of this application.

Commissioner of Patents

# Office Action Summary

Application No. 08/462,742 Applicant(s)

Examiner

Leon Radomsky

Zhang et al. Group Art Unit 1104

ince this application is FINAL.  Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.  In accordance with the practice under the provisions of the may be obtained under the provisions of CRR 1.136(a).  Position of Claims  In accordance of Claims  In accordance with the provisions of Extensions of time may be obtained under the provisions of CRR 1.136(a).  In accordance of Claims  In accordance with the provisions of CRR 1.136(a).  In accordance with data and the application.  In accordance with the provisions of CRR 1.136(a).  In accordance with data and the application.  In accordance with the provisions of time may be obtained under the provisions o		
Since this application is in condition for allowance except for formal interes, principles in accordance with the practice under Ex parte Quayle, 1935 C.D. 11; 453 O.G. 213.  in accordance with the practice under Ex parte Quayle, 1935 C.D. 11; 453 O.G. 213.  shortened statutory period for response to this action is set to expire 3 month(s), or thirty days, whichever shortened statutory period for response will cause the onger, from the making date of this communication. Failure to respond within the period for response will cause the oligible of the control of Claims and the provisions of time may be obtained under the provisions of CRR 1.136(a).  **Claim(s) 3.12 and 14.26	Responsive to communication(s) filed on Jul 29, 199	6
in accordance with the practice of this action is set to expire 3 month(s), or thirty days, winders shortened statutory period for response to this action is set to expire 3 month(s), or thirty days, winders donger, from the mailing date of this communication. Failure to respond within the period for response will cause the longer, from the mailing date of this communication. Failure to respond within the period for response will cause the longer from the mailing date of this communication. Failure to respond within the period for response will cause the longer from the mailing date of the provisions of Creft 1.1861.  **Claim(s) 3-12 and 14-26	This action is FINAL.	by the prosecution as to the merits is closed
shortened statutory period for response to this action is set to respond within the period for response will cause the longer, from the mailing date of this comminication. Failure to respond within the period for response will cause the longer, from the mailing date of this comminication.  (CFR 1.136(a).  **Sposition of Claims**  **Claim(s) 3-12 and 14-26**  Of the above, claim(s)	in accordance with the practice direct	athirty days, whichever
Claim(s)	aried for response to this action	is set to expire resid for response will cause the
Claim(s)	isposition of Claims	is/are pending in the application.
Claim(s)	X. Claim(s) 3-12 and 14-26	is/are withdrawn from consideration.
Claim(s) 3-12 and 14-26   is/are rejected.   Claim(s) 3-12 and 14-26   is/are objected to.   Claim(s)		
Claim(s)		
Claims		
Application Papers  See the attached Notice of Draftsperson's Patent Drawing Review, PTO-948.  The drawing(s) filed on	Claim(s)	is/are objected to
Application Papers  See the attached Notice of Draftsperson's Patent Drawing Review, PTO-948.  The drawing(s) filed on	Claims	are subject to restriction of election requirements
Attachment(s)  Notice of References Cited, PTO-892 Information Disclosure Statement(s), PTO-1449, Paper No(s). Interview Summary, PTO-413 Notice of Draftsperson's Patent Drawing Review, PTO-948 Notice of Informal Patent Application, PTO-152  SEE OFFICE ACTION ON THE FOLLOWING PAGES Part of Paper No.	Priority under 35 U.S.C. § 119  Acknowledgement is made of a claim for foreign and the CERTIFIE of the CERTIFI	gn priority under 35 U.S.C. § 119(a)-(d).  Discoples of the priority documents have been  e/Serial Number)  on from the International Bureau (PCT Rule 17.2(a)).
Information Disclosure Statement(s), PTO-1449, Paper Woldy.  Interview Summary, PTO-413  Notice of Draftsperson's Patent Drawing Review, PTO-948  Notice of Informal Patent Application, PTO-152  SEE OFFICE ACTION ON THE FOLLOWING PAGES	Attachment(S)	
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### DETAILED ACTION

# Claim Rejections - 35 USC § 103

- 1. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.
- 2. Claims 3-8,11-12,14-25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Oka (JP '915) in view of Liu et al. (US '826), as of record.
- 3. Claims 9-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Oka in view of Liu et al. as applied to claims 3-8,11-12,14-25 above, and further in view of Yonehara (US '093) or Shibata (US '224 or JP '224), as of record.
- 4. Claim 26 is rejected under 35 U.S.C. 103(a) as being unpatentable over Oka in view of Liu et al. as applied to claims 3-8,11-12,14-25 above, and further in view of Kuznetsov et al. (Microsc. Semicond. Mater. Conf. '93). Oka and Liu do not teach SIMS testing of the metal concentration.

Kuznetsov teaches determining Ni concentration in metal induced crystallized silicon using SIMS (Section 2).

Therefore, it would have been obvious to one of ordinary skill in the art to test the metal induced crystallized silicon of Oka by SIMS to check for the presence of and to determine the distribution of deleterious metal impurities (Oka, Pages 10-11 of translation) as taught by Kuznetsov.

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## Response to Arguments

5. Applicant's arguments filed 4-26-96 have been fully considered but they are not persuasive.

Applicants argue that Oka does not disclose a crystal growth direction parallel to the surface of the substrate. However, Oka does teach that grains nucleate in the seed region (204,403) (Fig. 2b,4) and subsequently grain growth proceeds parallel to the substrate through the connecting region (402) (Fig. 4) to the active island region (205, 404) (Fig. 2c,4).

Applicants argue that even if Oka teaches a crystal growth direction parallel to the surface of the substrate, Liu teaches grain growth perpendicular to the substrate, and therefore, Oka and Liu are incompatible. Examiner agrees that Liu teaches perpendicular grain growth in regions only where the metal catalyst is formed. However, examiner disagrees that Oka and Liu are incompatible. Oka teaches that at first small grains grow perpendicular to the substrate directly under the metal region (203) after a first anneal (Page 10 of translation), then the metal (203) is removed and the grain growth proceeds parallel to the substrate during a second anneal (Page 11). Thus, Oka and Liu are not incompatible because Oka's method includes both the method of Liu (perpendicular grain growth) and the parallel grain growth. Therefore, one of ordinary skill in the art would recognize that both perpendicular and parallel metal enhanced grain growth occurs from the teaching of Oka, and such a person would be motivated to use metal enhanced grain growth to form polysilicon driver TFTs in the recrystallized areas and amorphous pixel TFTs in the uncrystallized areas, as taught by Liu. Also, one of ordinary skill in the art would be

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motivated to form the polysilicon driver TFTs of Liu in the parallel grain growth areas rather than in the perpendicular growth areas because the parallel growth areas contain a smaller amount of deleterious metal impurity than perpendicular growth areas, as taught by Oka, Pages 10-11 and because the parallel growth areas contain superior quality grains compared to perpendicular growth areas, which may contain multiple crystal nuclei (i.e. small grains and large numbers of grain boundaries) as taught by Oka, bottom of Page 11.

#### Conclusion

6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for response to this final action is set to expire THREE MONTHS from the date of this action. In the event a first response is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event will the statutory period for response expire later than SIX MONTHS from the date of this final action.

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This office action has been created under the Patent and Trademark Office Semiconductor Technology Quality Assurance Pilot Program. It incorporates the examination quality standards set as a result of customer focus sessions with the semiconductor industry. The listing of the field of search to follow is one of these standards.

Field of Search	Date
U.S. Class and subclass: 437/21,40TFT,41TFT,88,99,101,109,174,233 148/Dig. 16,150.	10/95 & 10/96
Other Documentation:	
Electronic data base(s): USPAT JPOABS INSPEC	9/95 & 10/95

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to **Leon Radomsky** whose telephone number is (703) 305-3445.

Any inquiry of a general nature or relating to the status of this application should be directed to the Group receptionist whose telephone number is (703) 308-0661. Group 1100 fax number is (703) 305-3600.

CHARLES L. BOWERS, JR.
SUPERVISORY PATENT EXAMINER
GROUP 1100

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10/2/96